

1.5A Low Voltage Low Dropout CMOS Regulator

FEATURES

- Output Voltage Available in 1.5V. 1.8V. 2.5V. 2.8V, 2.85V, 3.0V, 3.3V, 5.0 V
- Stable with a Ceramic Output Capacitor of 4.7uF or Higher
- Low Dropout Voltage: 600mV at 1.5A
- Typical low Quiescent Current 95uA
- Over Temperature Shutdown
- Short Circuit Protection

APPLICATIONS

SATA Power Supply

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- Low Temperature Coefficient
- Standard SOT223-3L, TO252-3L and TO263-3L Packages.

GENERAL DESCRIPTION The LSP2159 is a 1.5A CMOS LDO regulator that

features a low quiescent current, ultra low input, output and dropout voltages, as well as over temperature shutdown. It is available in SOT223-3L. TO252-3L and TO263-3L packages. The fixed output voltage of the LSP2159 is set at the factory and trimmed to $\pm 2\%$. The LSP2159 is stable with a ceramic output capacitor of 4.7uF or higher.

This family of regulators can provide either a stand-alone power supply solution or act as a post regulator for switch mode power supplies. They are particularly well suited for applications requiring low input and output voltage.

Wireless Devices **Communication Devices**

LCD TV/ Monitors

- Portable Electronics
- Post Regulator for SMPS

PIN CONFIGURATION TO252-3L TO263-3L SOT223-3L (Top View) (Top View) (Top View) 3 3 3 2 2 2 1 1 1 Tab is Pin 2 Tab is Pin 2 Tab is Pin 2

PIN DESCRIPTION

Pin N	lumber				
SOT223-3L TO252-3L TO263-3L	TO252-3L TO252-3L B type		Pin Function		
1	3	VIN	Input		
2,TAB	1	GND	Ground		
3	2,TAB	VOUT	Output		

Please be aware that an Important Notice concerning availability, disclaimers, and use in critical applications of LSC products is at the end of this document.



BLOCK DIAGRAM

1.5A Low Voltage Low Dropout CMOS Regulator

ουт -0 Pł. OuerCurren Shuidown Thermal Shuidown R13 AMÊ R2 GND -0 **TYPICAL APPLICATIONS CIRCUITS** LSP2159 Vout V_{IN}O VIN Vout GND **C1** C2 4.7µF 1μF

ABSOLUTE MAXIMUM RATINGS

Parameter	Rating	Unit	
Input Supply Voltage, EN Pin Volt	+6	V	
Maximum Output Current		PD/(VIN-VO)	
Output Pin Voltage		-0.3 to VIN+0.3	V
	SOT223-3L	625	
Internal Power Dissipation	TO252-3L	1200	mW
	TO263-3L	1600	
	SOT223-3L	7	
Junction to Case Thermal Resistance (θ_{JC})	TO252-3L	7	/ W
	TO263-3L	2.7]
	SOT223-3L	160	
Junction to Ambient Thermal Resistance (θ_{JA})	TO252-3L	90	/ W
	TO263-3L	45	
Operating temperature		-40 to 85	°C
Operating Junction Temperatur	-40 to 125	°C	
Storage Temperature	-65 to 150	°C	
Maximum Junction Temperatur	150	°C	
Lead Temperature (Soldering, 5 s	300	°C	

Note: These are stress ratings only and functional operation is not implied. Exposure to absolute maximum ratings for prolonged time periods may affect device reliability. All voltages are with respect to ground.



Liteon Semiconductor Corporation LSP2159

1.5A Low Voltage Low Dropout CMOS Regulator RECOMMENDED OPERATING CONDITIONS

Parameter	Rating	Unit
Input Supply Voltage	5.5	V
Operating temperature	-40 to 85	°C
Operating Junction Temperature	-40 to 125	°C
	-40 to 125	

ELECTRICAL CHARACTERISTICS

 $(V_{IN} = V_{OUT} + 0.5V, C_{IN} = 1\mu F, C_0 = 4.7\mu F, T_A = 25^{\circ}C$ unless otherwise specified.)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Input Voltage	V _{IN}			Note1		5.5	V
Output Voltage Accuracy	Vo	l	_o = 100mA	-2		+2	%
Short Circuit Current	I _{SC}	,	V ₀ < 0.3V			1.0	А
Ground Current	I _{GND}	I _O =	1mA to 1.5A	N N		600	μA
Quiescent Current	Ι _Q		V _o = 0mA		60	80	μA
		$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$		14	0.5	1	
Line Regulation	LNR			0.5	1	%/V	
Load Regulation	LDR	$I_0 = 1 \text{ mA to } 1.5 \text{ A}$			0.5	2	%/A
Temperature Coefficient	Tc				30		ppm/°C
Over Temperature Shutdown	OTS				150		°C
Over Temperature Hystersis	ОТН				30		°C
			f=100Hz		65		
Power Supply Ripple Rejection	PSRR	I ₀ = 100mA V₀ =1.5V	f= 1KHz		55		dB
		v ₀ 1.0 v	f= 10KHz		35		
(\sim)			$1.5V \le V_0 < 2.5V$		1300		
Dropout Voltage	VDROP	I ₀ = 1.5A	$2.5V \le V_0 < 2.8V$		800		mV
			V ₀ ≥2.8V		300		
Output Noise	Vn V	(f = 10	Hz to 100kHz		40		μV_{RMS}

Note 1 : The minimum input voltage of the LSP2159 is determined by output voltage and dropout voltage. The minimum input voltage is defined as:

V_{IN(MIN)}=V_O+V_{DROR}

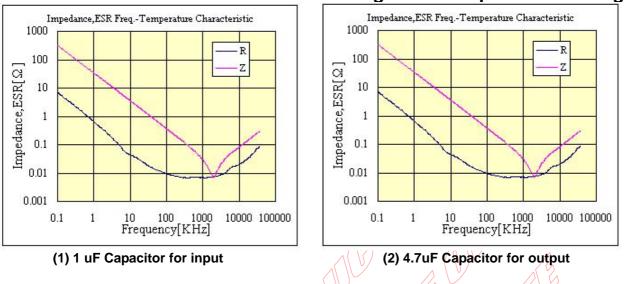
APPLICATION INFORMATION

The LSP2159 families of low-dropout (LDO) regulators have several features that allow them to apply to a wide range of applications. The family operates with very low input voltage (1.4V) and low dropout voltage (typically 150mV at full load), making it an efficient stand-alone power supply or post regulator for battery or switch mode power supplies. The 1.5A output current make the LSP2159 family suitable for powering many microprocessors and FPGA supplies. The LSP2159 family also has low output noise (typically 40µVRMS with 4.7µF output capacitor), making it ideal for use in telecom equipment.

External Capacitor Requirements

A 4.7µF or larger ceramic input bypass capacitor, connected between VIN and GND and located close to the LSP2159, is required for stability. A 1.0uF minimum value capacitor from VO to GND is also required. To improve transient response, noise rejection, and ripple rejection.





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Regulator Protection

The LSP2159 features internal current limiting, thermal protection and short circuit protection. During normal operation, the LSP2159 limits output current to about 3A. When current limiting engages, the output voltage scales back linearly until the over current condition ends. While current limiting is designed to prevent gross device failure, care should be taken not to exceed the power dissipation ratings of the package. If the temperature of the device exceeds 150°C, thermal-protection circuitry will shut down. Once the device has cooled down to approximately 30°C below the high temp trip point, regulator operation resumes. The short circuit current of the LSP2159 is about 1A when its output pin is shorted to ground.

Thermal Information

The amount of heat that an LDQ linear regulator generates is:

$\mathsf{P}_{\mathsf{D}}=(\mathsf{V}_{\mathsf{IN}}-\mathsf{V}_{\mathsf{O}})\mathsf{I}_{\mathsf{O}}.$

All integrated circuits have a maximum allowable junction temperature $(T_J max)$ above which normal operation is not assured. A system designer must design the operating environment so that the operating junction temperature (T_J) does not exceed the maximum junction temperature $(T_J max)$. The two main environmental variables that a designer can use to improve thermal performance are air flow and external heatsinks. The purpose of this information is to aid the designer in determining the proper operating environment for a linear regulator that is operating at a specific power level.

In general, the maximum expected power (P_{D(max})) consumed by a linear regulator is computed as:

$$P_{D(MAX)} = \left(V_{I(avg)} - V_{O(avg)}\right)I_{O(avg)} + V_{I(avg)}I_{(Q)}$$

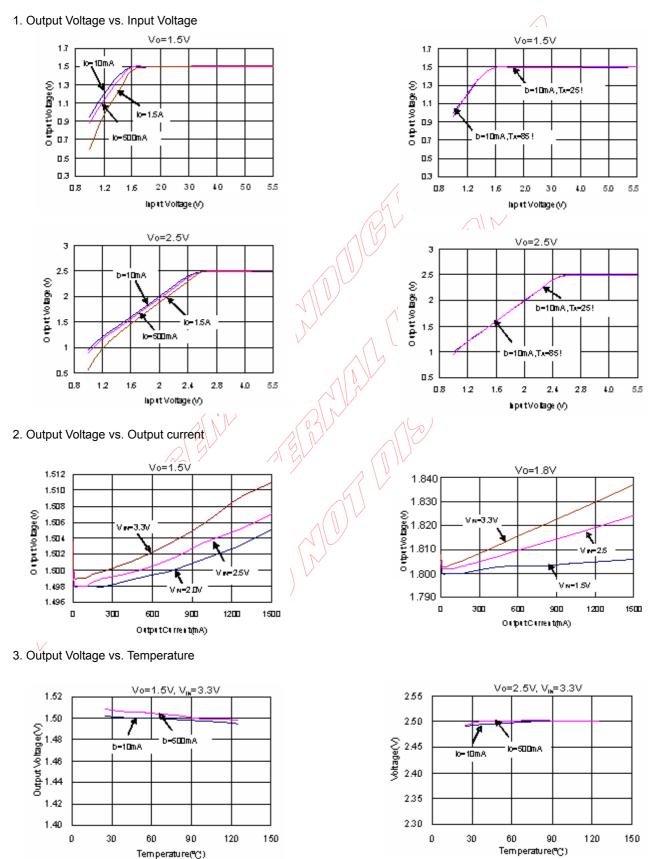
Where:

 $V_{I (avg)}$ is the average input voltage. $V_{O(avg)}$ is the average output voltage. $I_{O(avg)}$ is the average output current. $I_{(Q)}$ is the quiescent current.

For most LDO regulators, the quiescent current is insignificant compared to the average output current; therefore, the term $V_{I(avg)} \times I_{(Q)}$ can be neglected. The operating junction temperature is computed by adding the ambient temperature (T_A) and the increase in temperature due to the regulator's power dissipation. The temperature rise is computed by multiplying the maximum expected power dissipation by the sum of the thermal resistances between the junction and the case (R_{θJC}), the case to heatsink (R_{θCS}), and the heatsink to ambient (R_{θSA}). Thermal resistances are measures of how effectively an object dissipates heat. Typically, the larger the devices, the more surface area available for power dissipation so that the object's thermal resistance will be lower.



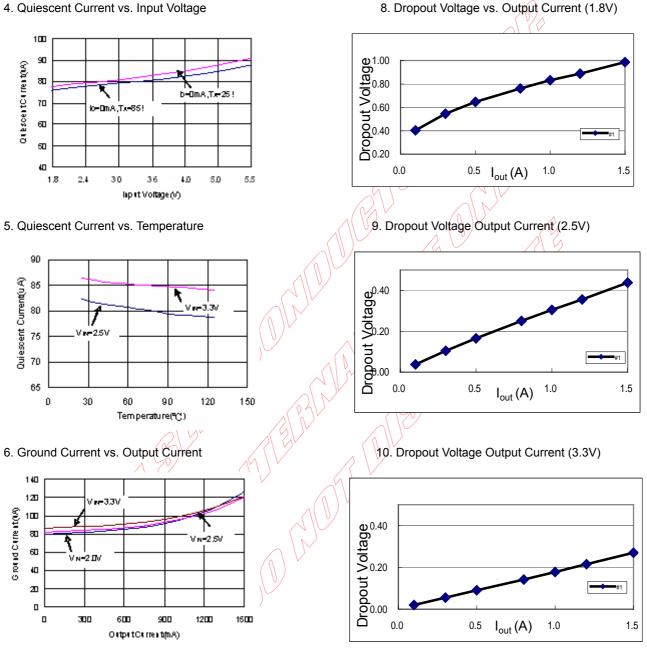
1.5A Low Voltage Low Dropout CMOS Regulator ■ TYPICAL PERFORMANCE CHARACTERISTICS



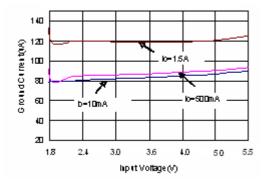


[®] Liteon Semiconductor Corporation LSP2159

1.5A Low Voltage Low Dropout CMOS Regulator TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)



7. Ground Current vs. Input Voltage





1.5A Low Voltage Low Dropout CMOS Regulator

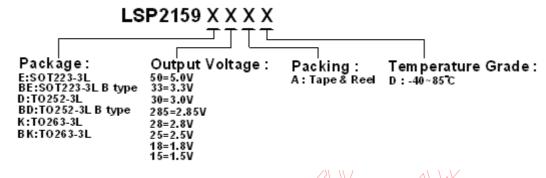
TYPICAL PERFORMANCE CHARACTERISTICS (CONTINUED)

11. Load Transient Response 100mV >4M 400µs | A Ch3 J 410 A cho 410: chs 230mA Suumo Vo=1.5V,V_B=3.3V, Io=10mA to 500mA Vo=1.5V,V 3.3V, lo= 10mA to 1.5A M WALL MUNICIPAL L The DIA Staur



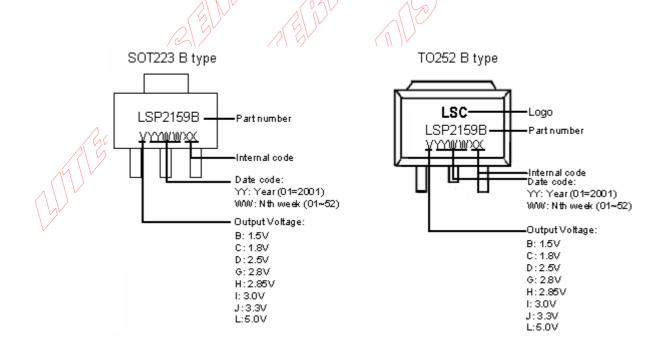
1.5A Low Voltage Low Dropout CMOS Regulator

ORDERING INFORMATION



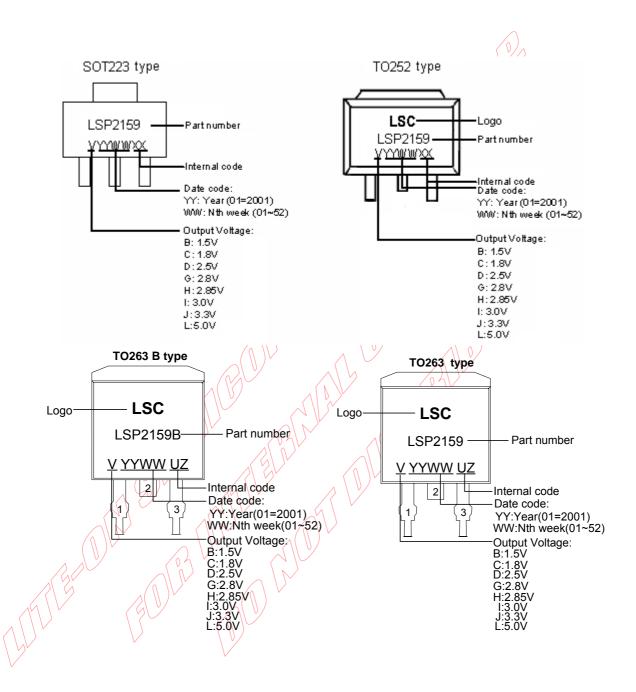
		Tape &		
Package Code	Package	Quantity	Part Number Suffix	Temperature
E	SOT223-3L	2500	A	D : -40°C~85°C
E	SOT223-3L	2500		D : -40°C~85°C
D	TO252-3L	2500	A	D : -40°C~85°C
D	TO252-3L	2500	A	D : -40°C~85°C
K	TO263-3L	800	A	D : -40°C~85°C
K	TO263-3L	800	A	D : -40°C~85°C
	E E D D K	E SOT223-3L E SOT223-3L D TO252-3L D TO252-3L K TO263-3L	Package Code Package Quantity E SOT223-3L 2500 E SOT223-3L 2500 D TO252-3L 2500 D TO252-3L 2500 K TO263-3L 800	E SOT223-3L 2500 A E SOT223-3L 2500 A D TO252-3L 2500 A D TO252-3L 2500 A K TO263-3L 800 A

MARKING INFORMATION





1.5A Low Voltage Low Dropout CMOS Regulator

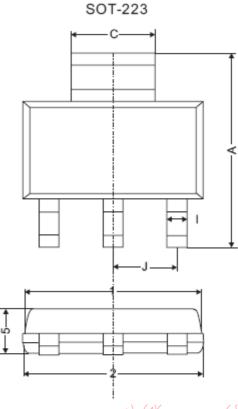




1.5A Low Voltage Low Dropout CMOS Regulator

■ PACKAGE INFORMATION

(1). SOT223-3L

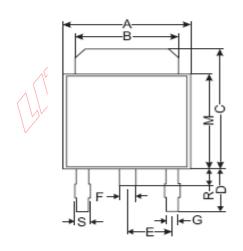


Dimer	sions	Millime	ter)	1
Symbol	MIN	NOM	MAX	
A	6.70	7.00	7.30	
С	2.90	3.00	3.10	
D	0.02	0.06	0.10	
E	0°	5°	10°	
	0.60	0.70	0.80	
Н	0.25	0.30	0.35	
В		13º TYF	D	
J	2	.30 RE		
1	6.30	6.50	6.70	
2	6.30	6.50	6.70	
3	3.30	3.50	3.70	
4	3.30	3.50	3.70	
5	1.40	1.60	1.80	
-	3)	+ ←B	
\angle			7	£

(2).TO252-3L



To-252





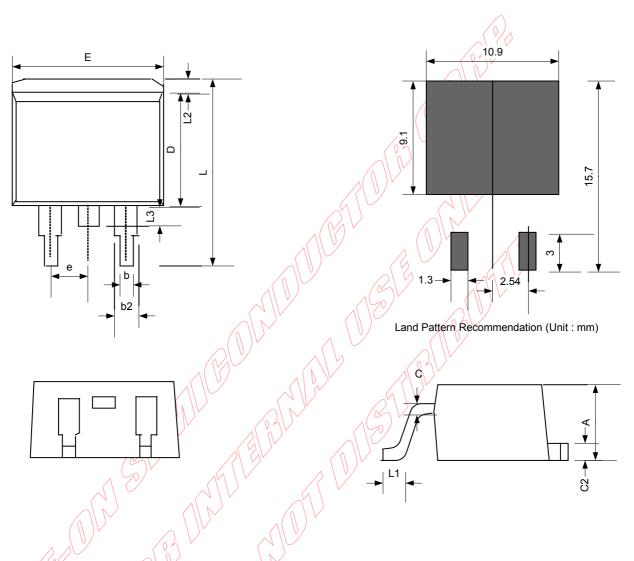
Dimensions(Millimeter)						
Symbol	MIN NOM MAX					
A	6.40	6.60	6.80			
В	5.20	5.35	5.50			
С	6.80	7.00	7.20			
D	2.20	2.50	2.80			
E	2.30 REF.					
F	0.70	0.80	0.90			
S	0.60	0.75	0.90			
G	0.50	0.60	0.70			
Н	2.20	2.30	2.40			
J	0.45	0.50	0.55			
К	0	0.07	0.15			
L	0.90	1.20	1.50			
М	5.40	5.60	5.80			
R	0.80	1.00	1.20			





(2).TO263-3L

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Symbol	Dimensions In Millimeters			Dimensions In Inches			
Symbol	Min.	Nom.	Max.	Min.	Nom.	Max.	
A	4.06	4.45	4.83	0.160	0.175	0.190	
b	0.51	0.75	0.99	0.020	0.030	0.039	
b2	1.14	1.27	1.40	0.045	0.050	0.055	
С		0.38TYP.			0.015TYP.		
C2	1.14	1.27	1.40	0.045	0.050	0.055	
D	8.65	9.15	9.65	0.341	0.360	0.380	
Е	9.65	9.97	10.29	0.380	0.393	0.405	
е		2.54BSC.		0.100BSC.			
L	14.61	15.24	15.88	0.575	0.600	0.625	
L1	2.28	2.54	2.80	0.090	0.100	0.110	
L2		1.30	2.92		0.051	0.115	
L3	1.27	1.52	1.78	0.050	0.060	0.070	



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